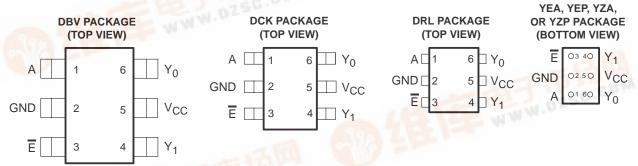
#### 专业PCB打样工厂,24小时加急SN74AUC1G19 查询SN74AUC1G19供应商 1-OF-2 DECODER/DEMULTIPLEXER SCES626B - MARCH 2005 - JUNE 2005 Available in the Texas Instruments Max t<sub>pd</sub> of 3 ns at 1.8 V V<sub>CC</sub> NanoStar<sup>™</sup> and NanoFree<sup>™</sup> Package Low Power Consumption, 10-µA Max ICC Optimized for 1.8-V Operation and is 3.6-V Latch-Up Performance Exceeds 100 mA Per I/O Tolerant to Support Mixed-Mode Signal JESD 78. Class II Operation ESD Protection Exceeds JESD 22 Ioff Supports Partial-Power-Down Mode – 2000-V Human-Body Model (A114-A) Operation – 200-V Machine Model (A115-A) - 1000-V Charged-Device Model (C101) Sub-1-V Operable

±8-mA Output Drive at 1.8 V V<sub>CC</sub>



See mechanical drawings for dimensions.

### description/ordering information

This 1-of-2 decoder/demultiplexer is operational at 0.8-V to 2.7-V V<sub>CC</sub>, but is designed specifically for 1.65-V to 1.95-V V<sub>CC</sub> operation.

The SN74AUC1G19 is a 1-of-2 decoder/demultiplexer. This device buffers the data on input A and passes it to the outputs  $Y_0$  (true) and  $Y_1$  (complement) when the enable ( $\overline{E}$ ) input signal is low.

NanoStar<sup>™</sup> and NanoFree<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

TA	PACKAGET		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>‡</sup>	
<b>191</b>	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP		SN74AUC1G19YEPR		
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUC1G19YZPR	U5_	
–40°C to 85°C		Reel of 3000	SN74AUC1G19DBVR	U19_	
	SOT (SOT-23) – DBV	Reel of 250	SN74AUC1G19DBVT	U19_	
		Reel of 3000	SN74AUC1G19DCKR	115	
	SOT (SC-70) – DCK	Reel of 250	SN74AUC1G19DCKT	- U5_	
	SOT (SOT-553) – DRL	Reel of 4000	SN74AUC1G19DRLR	U5_	

### **ORDERING INFORMATION**

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

DBV/DCK/DRL: The actual top-side marking has one additional character that designates the assembly/test site.

YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition  $(1 = SnPb, \bullet = Pb-free).$ 



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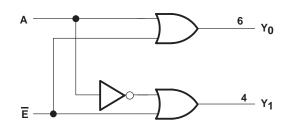
#### description/ordering information

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

For more information about AUC Little Logic devices, please refer to the TI application report, *Applications of Texas Instruments AUC Sub–1–V Little Logic Devices*, literature number SCEA027.

FUNCTION TABLE							
INPUTS		OUTPUTS					
Ē	Α	Y <sub>0</sub>	Y <sub>1</sub>				
L	L	L	Н				
L	Н	Н	L				
Н	Х	Н	Н				

#### logic diagram (positive logic)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, V $_{CC}$ Input voltage range, V $_{I}$ (see Note 1)	
Voltage range applied to any output in the high-impedance or power-off state, V <sub>O</sub> (see Note 1)	–0.5 V to 3.6 V
Voltage range applied to any output in the high or low state, $V_{O}$	
(see Note 1 and Note 2)	–0.5 V to V <sub>CC</sub> + 0.5 V
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	
Continuous output current, I <sub>O</sub>	
Continuous current through V <sub>CC</sub> or GND	
Package thermal impedance, $\theta_{IA}$ (see Note 3): DBV package	
DCK package	
DRL package	
YEP/YZP package	
Storage temperature range, T <sub>stg</sub>	

<sup>+</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The value of V<sub>CC</sub> is provided in the recommended operating conditions table.

3. The package thermal impedance is calculated in accordance with JESD 51-7.



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### recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
VCC	Supply voltage	Operating	0.8	2.7	V
		V <sub>CC</sub> = 0.8 V	VCC	3.6	V
VIH	High-level control input voltage	V <sub>CC</sub> = 1.1 V to 1.95 V	$0.65 \times V_{CC}$	3.6	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7	3.6	V
		$V_{CC} = 0.8 V$		0	V
VIL	Low-level control input voltage	V <sub>CC</sub> = 1.1 V to 1.95 V	0	$0.35 \times V_{CC}$	
		V <sub>CC</sub> = 2.3 V to 2.7 V	0	0.7	V
Vo	Output voltage		0	VCC	V
		V <sub>CC</sub> = 0.8 V		-0.7	
		V <sub>CC</sub> = 1.1 V		-3	
ЮН	High-level control output current	V <sub>CC</sub> = 1.4 V		-5	mA
-		V <sub>CC</sub> = 1.65 V		-8	
		V <sub>CC</sub> = 2.3 V		-9	
		V <sub>CC</sub> = 0.8 V		0.7	
		$V_{CC} = 1.1 V$		3	
IOL	Low-level control output current	V <sub>CC</sub> = 1.4 V		5	mA
-		V <sub>CC</sub> = 1.65 V		8	
		V <sub>CC</sub> = 2.3 V		9	
		V <sub>CC</sub> = 0.8 V to 1.95 V		20	ns/V
$\Delta t/\Delta v$ In	Input transition rise or fall rate	V <sub>CC</sub> = 2.3 V to 2.7 V		15	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP <sup>†</sup>	MAX	UNIT
	I <sub>OH</sub> = -100 μA	0.8 V to 2.7 V	V <sub>CC</sub> – 0.1			
	I <sub>OH</sub> = -0.7 mA	0.8 V		0.55		
	$I_{OH} = -3 \text{ mA}$	1.1 V	0.8			
VOH	$I_{OH} = -5 \text{ mA}$	1.4 V	1			V
	$I_{OH} = -8 \text{ mA}$	1.65 V	1.2			
	$I_{OH} = -9 \text{ mA}$					
	I <sub>OL</sub> = 100 μA	0.8 V to 2.7 V			0.2	
	I <sub>OL</sub> = 0.7 mA	0.8 V		0.25		V
	I <sub>OL</sub> = 3 mA	1.1 V			0.3	
V <sub>OL</sub>	I <sub>OL</sub> = 5 mA	1.4 V			0.4	
	I <sub>OL</sub> = 8 mA	1.65 V			0.45	
	I <sub>OL</sub> = 9 mA	2.3 V			0.6	
lj	$V_I = V_{CC}$ or GND	0 to 2.7 V			±5	μΑ
loff	$V_{I}$ or $V_{O} = 2.7 V$	0			±10	μΑ
ICC	$V_{I} = V_{CC} \text{ or GND},$ $I_{O} = 0$	0.8 V to 2.7 V			10	μΑ
Ci	$V_{I} = V_{CC} \text{ or } GND$	2.5 V		2.5		pF

<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V (unless otherwise noted), T<sub>A</sub> = 25°C.



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switching characteristics over recommended operating free-air temperature range,  $C_L = 15 \text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	-	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.1 V ± 0.1 V		V <sub>CC</sub> = 1.5 V ± 0.1 V		V <sub>CC</sub> = 1.8 V ± 0.15 V		$\begin{array}{c} \text{V}_{\text{CC}} = 2.5 \text{ V} \\ \pm \text{ 0.2 V} \end{array}$		UNIT
	(INPUT)		TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
<sup>t</sup> pd	A or E	Y	7.5	0.5	4.6	0.4	3.0	0.3	2.4	0.2	1.7	ns

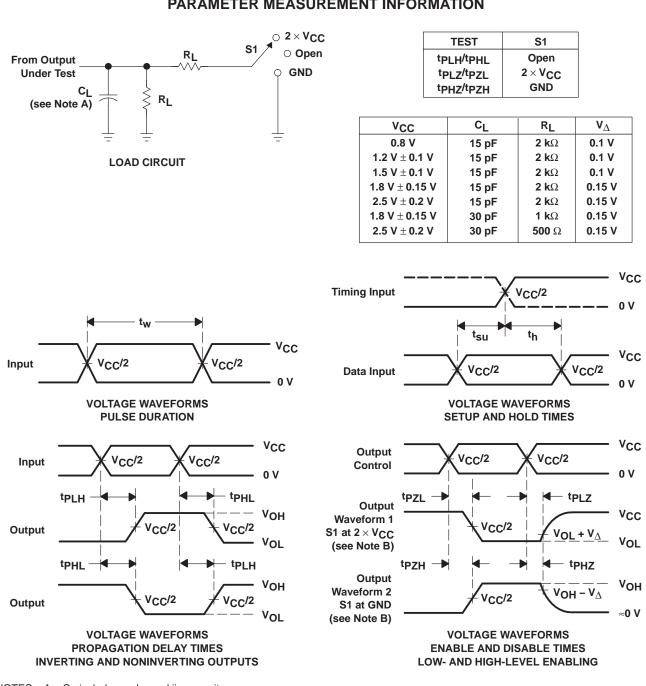
switching characteristics over recommended operating free-air temperature range,  $C_L = 30 \text{ pF}$  (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		UNIT
	(INPOT)	(001901)	MIN	MAX	MIN	MAX	
<sup>t</sup> pd	A or E	Y <sub>0</sub> or Y <sub>1</sub>	0.5	2.8	0.4	2.0	ns

### operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 0.8 V TYP	V <sub>CC</sub> = 1.2 V TYP	V <sub>CC</sub> = 1.5 V TYP	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	f = 10 MHz	13	13	13	13	14	pF

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PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>Q</sub> = 50  $\Omega$ , slew rate  $\geq$  1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. tPLZ and tPHZ are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

#### Figure 1. Load Circuit and Voltage Waveforms





# PACKAGE OPTION ADDENDUM

6-Jun-2005

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74AUC1G19DBVR	ACTIVE	SOT-23	DBV	6	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G19DBVRE4	ACTIVE	SOT-23	DBV	6	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G19DBVT	ACTIVE	SOT-23	DBV	6	250	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G19DBVTE4	ACTIVE	SOT-23	DBV	6	250	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G19DCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G19DCKRE4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G19DCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G19DCKTE4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G19DRLR	ACTIVE	SOP	DRL	6	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G19YEPR	ACTIVE	WCSP	YEP	6	3000	TBD	SNPB	Level-1-260C-UNLIM
SN74AUC1G19YZPR	ACTIVE	WCSP	YZP	6	3000	Pb-Free (RoHS)	SNAGCU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

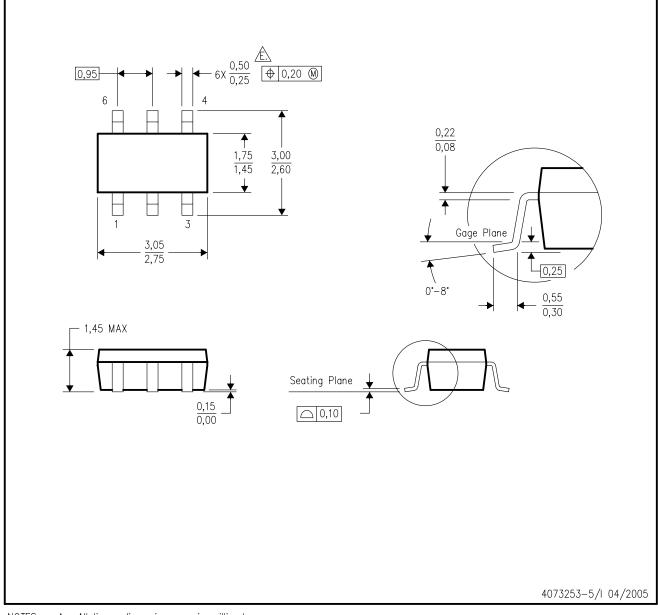
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DBV (R-PDSO-G6)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion.D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- E Falls within JEDEC MO-178 Variation AB, except minimum lead width.

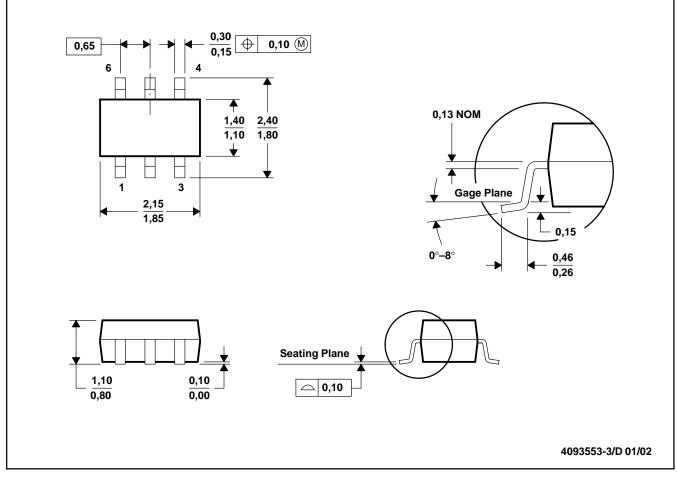


### **MECHANICAL DATA**

MPDS114 - FEBRUARY 2002

#### DCK (R-PDSO-G6)

#### PLASTIC SMALL-OUTLINE PACKAGE



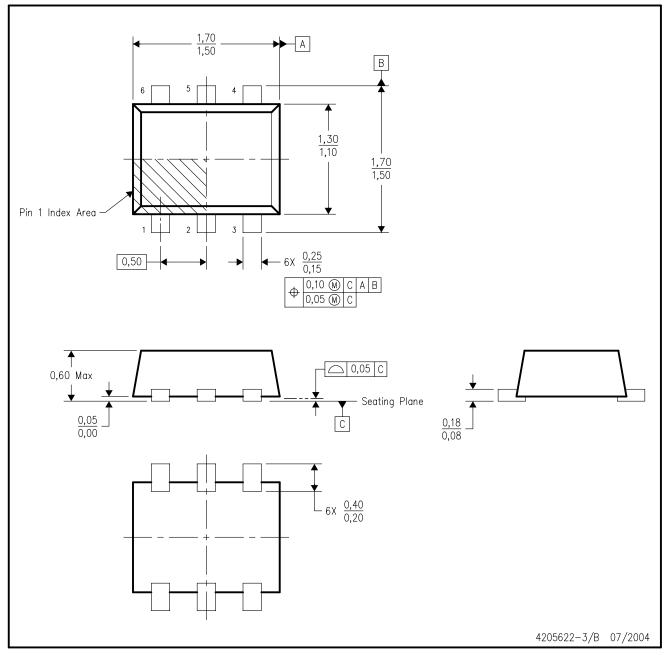
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-203



# DRL (R-PDSO-N6)

# PLASTIC SMALL OUTLINE



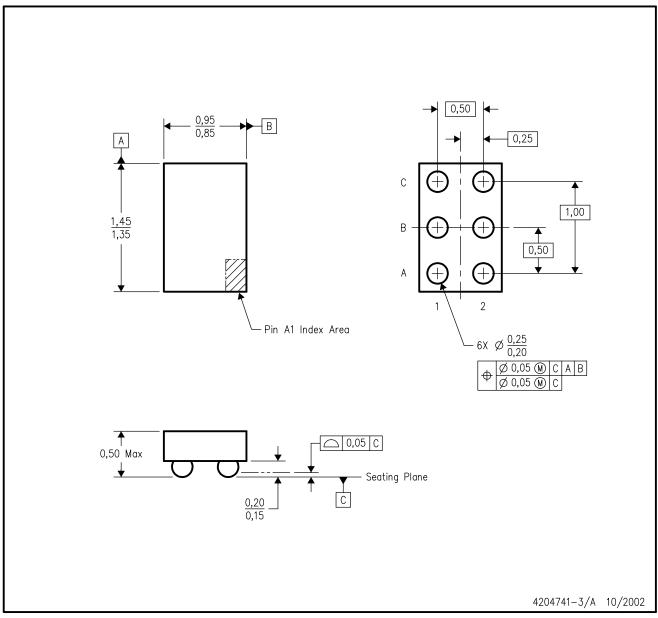
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. JEDEC package registration is pending.



YZP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



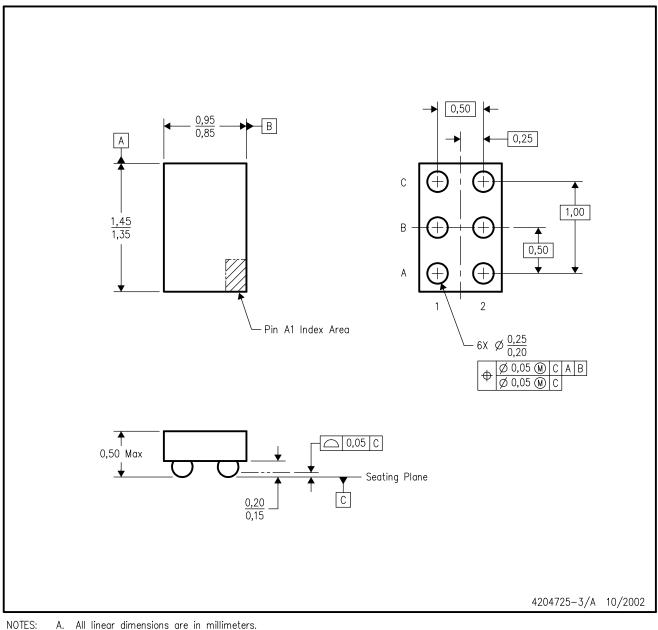
NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead-free. Refer to the 6 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.

YEP (R-XBGA-N6)

### DIE-SIZE BALL GRID ARRAY



NOTES:

- This drawing is subject to change without notice. Β.
- C. NanoStar™ package configuration.
- D. This package is tin-lead (SnPb). Refer to the 6 YZP package (drawing 4204741) for lead-free.

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